

Features

- Epitaxial Die Construction
- Two isolated NPN/PNP (TPBC847W+TPBC857W) Transistors in one package

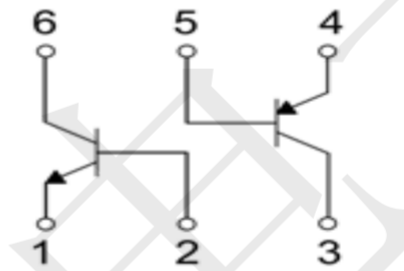
Ordering Information

- Case: SOT563
- Shipping Qty:3000/7inch Tape& Reel



Top View

SOT563



Absolute Maximum Ratings TR1 ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	45	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current –Continuous	0.1	A
P_C	Collector Power Dissipation	150	mW
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^\circ\text{C}$

Absolute Maximum Ratings TR2 ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-50	V
V_{CEO}	Collector-Emitter Voltage	-45	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current –Continuous	-0.1	A
P_C	Collector Power Dissipation	150	mW
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^\circ\text{C}$

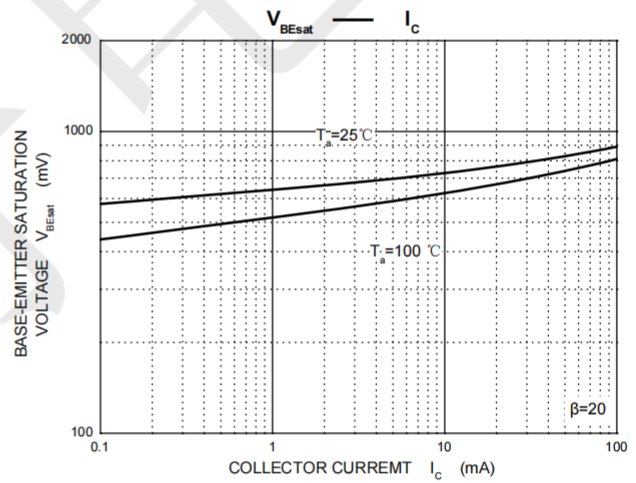
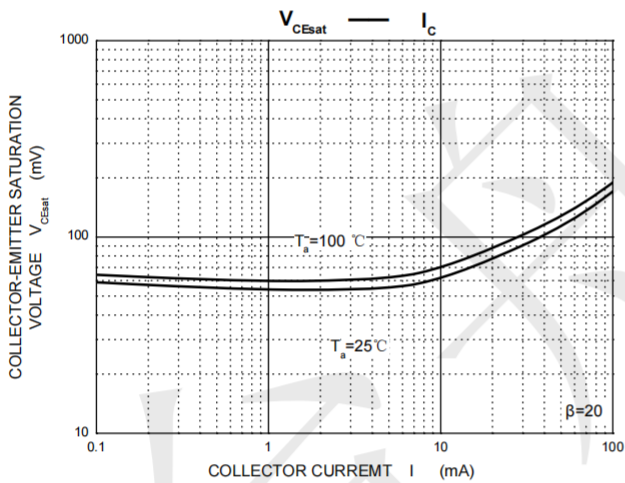
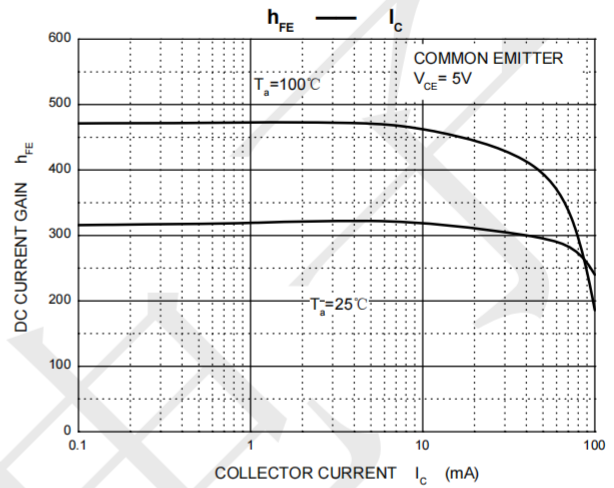
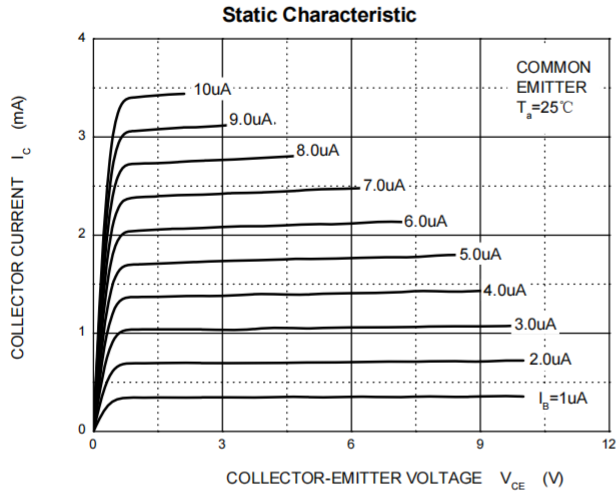
Electrical Characteristics TR1(NPN) ($T_A=25^\circ\text{C}$ unless otherwise noted)

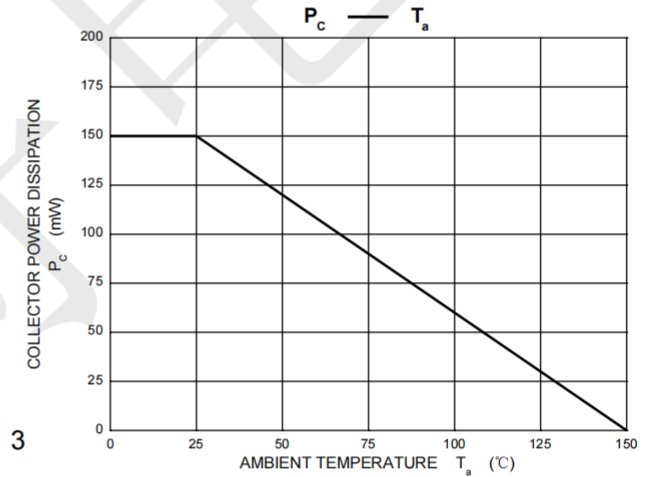
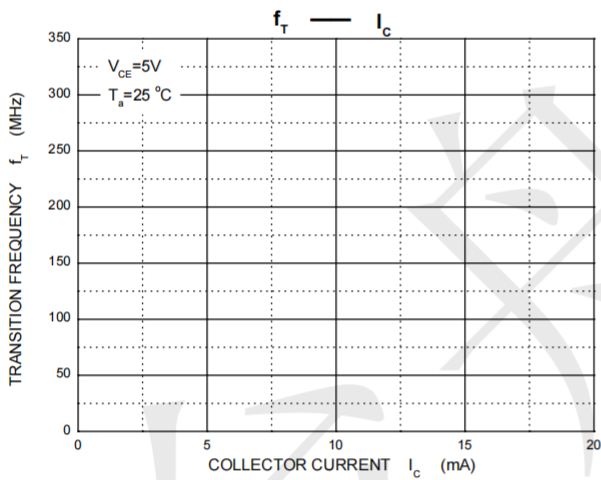
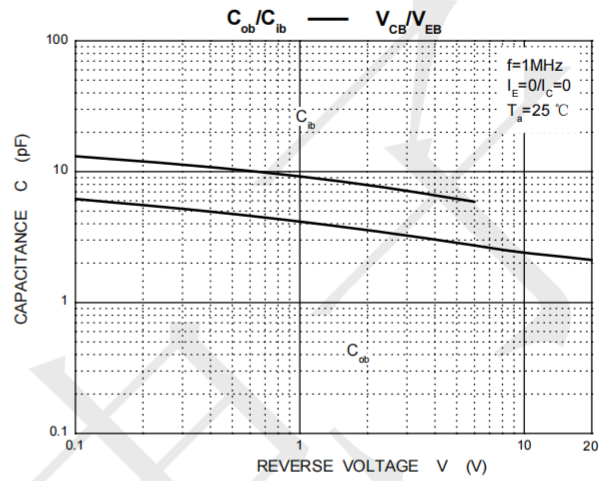
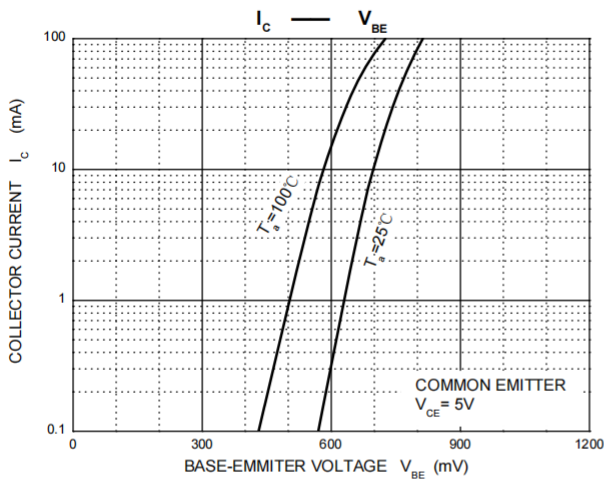
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=1\mu\text{A}, I_C=0$	6			V
Collector cut-off current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0$			15	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0$			15	nA
DC current gain	h_{FE}	$V_{CE}=5\text{V}, I_C=2\text{mA}$	200		450	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$			0.25	V
	$V_{CE(sat)}$	$I_C=100\text{mA}, I_B=5\text{mA}$			0.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$		0.7		V
	$V_{BE(sat)}$	$I_C=100\text{mA}, I_B=5\text{mA}$		0.9		V
Base-emitter voltage	$V_{BE(on)}$	$V_{CE}=5\text{V}, I_C=2\text{mA}$	0.58		0.7	V
	$V_{BE(on)}$	$V_{CE}=5\text{V}, I_C=10\text{mA}$			0.72	V
Collector output capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			6.0	pF
Transition frequency	f_T	$V_{CE}=5\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100			MHz
Noise figure	NF	$V_{CE}=5\text{V}, I_C=0.2\text{mA},$ $f=1\text{kHz}, R_g=2\text{K}\Omega, \Delta f=200\text{Hz}$			10	dB

Electrical Characteristics TR2(PNP) ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-10\mu\text{A}, I_E=0$	-50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-10\text{mA}, I_B=0$	-45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-1\mu\text{A}, I_C=0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB}=-30\text{V}, I_E=0$			-15	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=-5\text{V}, I_C=0$			-15	nA
DC current gain	h_{FE1}	$V_{CE}=-5\text{V}, I_C=-2\text{mA}$	220		475	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-10\text{mA}, I_B=-0.5\text{mA}$			-0.3	V
	$V_{CE(sat)}$	$I_C=-100\text{mA}, I_B=-5\text{mA}$			-0.65	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=-10\text{mA}, I_B=-0.5\text{mA}$		-0.7		V
	$V_{BE(sat)}$	$I_C=-100\text{mA}, I_B=-5\text{mA}$			-0.95	V
Base-emitter voltage	$V_{BE(on)}$	$V_{CE}=-5\text{V}, I_C=-2\text{mA}$	-0.6		-0.75	V
	$V_{BE(on)}$	$V_{CE}=-5\text{V}, I_C=-10\text{mA}$			-0.82	V
Collector output capacitance	C_{ob}	$V_{CB}=-10\text{V}, I_E=0, f=1\text{MHz}$			4.5	pF
Transition frequency	f_T	$V_{CE}=-5\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$	100			MHz
Noise figure	NF	$V_{CE}=-5\text{V}, I_C=-0.2\text{mA},$ $f=1\text{kHz}, R_g=2\text{K}\Omega, \Delta f=200\text{Hz}$			10	dB

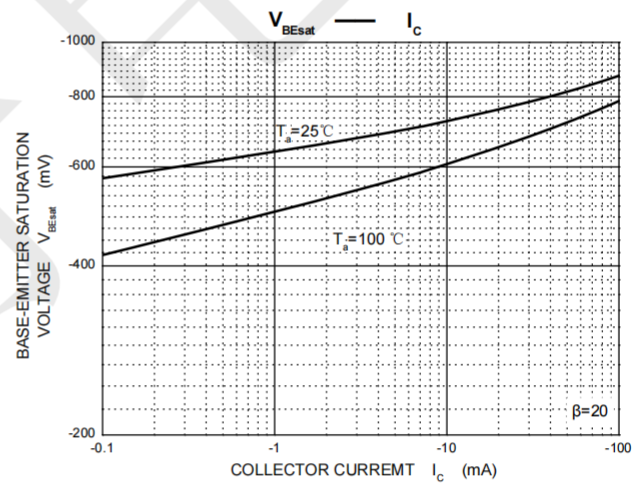
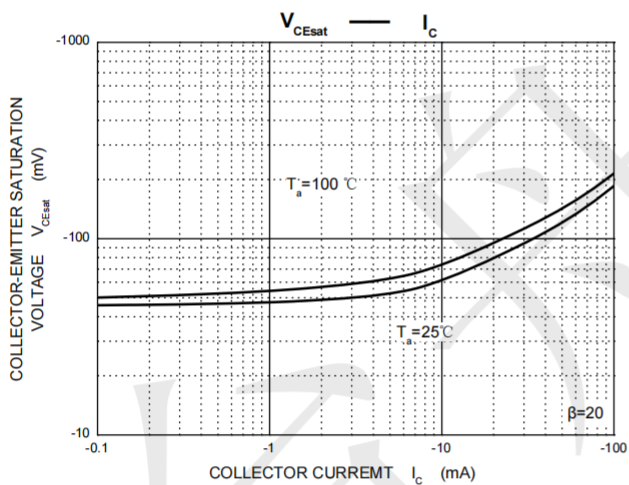
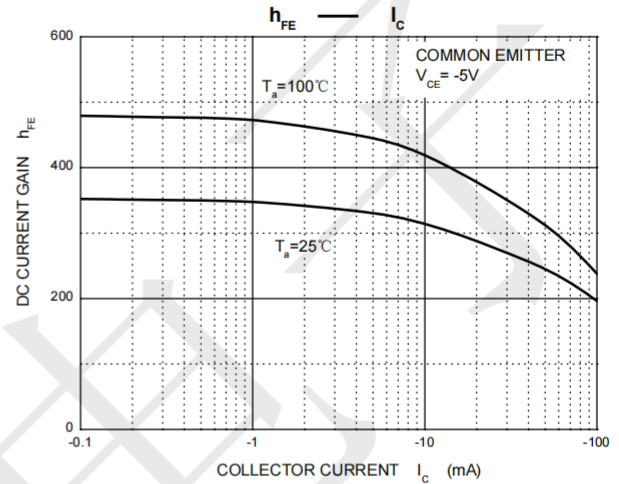
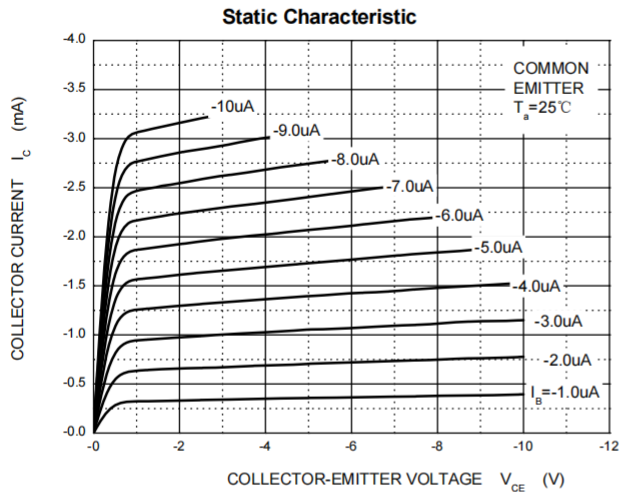
Typical Electrical Characteristic Curves (TR1)

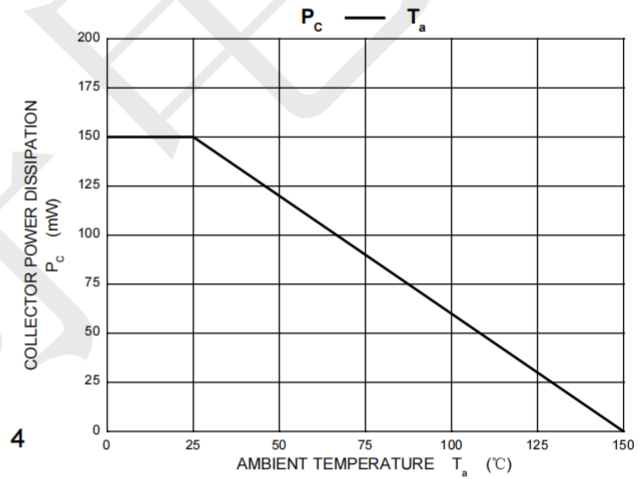
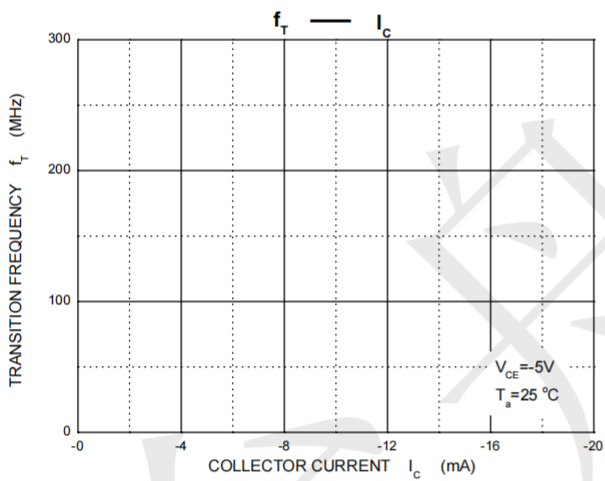
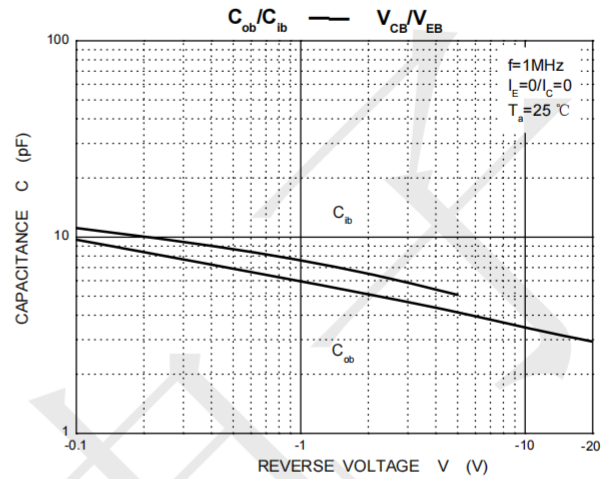
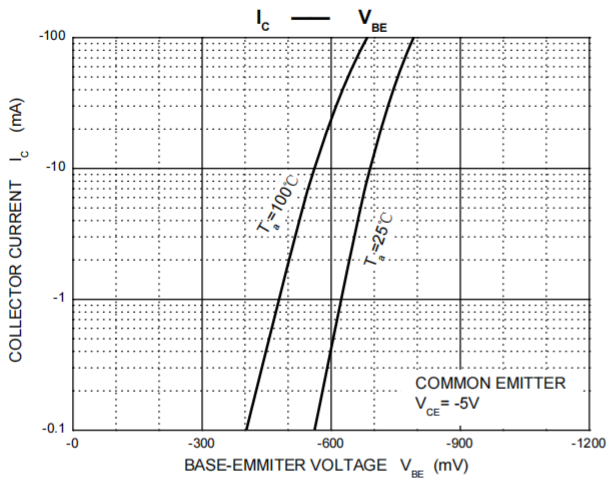




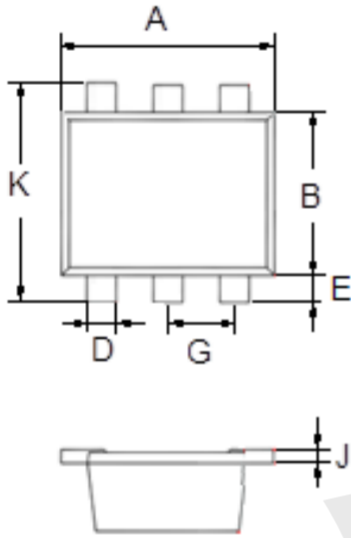
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Typical Electrical Characteristic Curves (TR2)





Outline Drawing - SOT563 (unit: mm)



SOT-563		
Dimension	Min.	Max.
A	1.500	1.700
B	1.100	1.300
C	0.525	0.600
D	0.170	0.270
E	0.100	0.300
G	0.450	0.550
H	0.000	0.050
J	0.090	0.160
K	1.500	1.700

Mounting Pad Layout-SOT563 (unit: mm)

